

<b>Notice of References Cited</b>			Application/Control No.	Applicant(s)/Patent Under Reexamination BARGE ET AL.	
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**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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**FOREIGN PATENT DOCUMENTS**

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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Sorab K. Ghandhi, VLSI Fabrication Principles: Silicon and Gallium Arsenide, 2 <sup>nd</sup> ed., 1994, John Wiley & Sons, Inc., New York, pp. 726
	V	
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